- 200-MHz Bandwidth
- 250-kΩ Input Resistance

- Selectable Nominal Amplification of 10, 100, or 400
- **No Frequency Compensation Required**

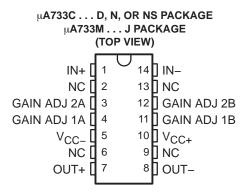
10**∏** IN−

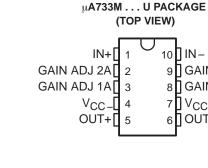
7 🛮 V_{CC+}

6∏OUT-

9 GAIN ADJ 2B

8 GAIN ADJ 1B





NC - No internal connection

description/ordering information

The µA733 is a monolithic two-stage video amplifier with differential inputs and differential outputs. Internal series-shunt feedback provides wide bandwidth, low phase distortion, and excellent gain stability. Emitter-follower outputs enable the device to drive capacitive loads, and all stages are current-source biased to obtain high common-mode and supply-voltage rejection ratios.

Fixed differential amplification of 10 V/V, 100 V/V, or 400 V/V may be selected without external components, or amplification may be adjusted from 10 V/V to 400 V/V by the use of a single external resistor connected between 1A and 1B. No external frequency-compensating components are required for any gain option.

The device is particularly useful in magnetic-tape or disc-file systems using phase or NRZ encoding and in high-speed thin-film or plated-wire memories. Other applications include general-purpose video and pulse amplifiers where wide bandwidth, low phase shift, and excellent gain stability are required.

The μA733C is characterized for operation from 0°C to 70°C; the μA733M is characterized for operation over the full military temperature range of -55°C to 125°C.

ORDERING INFORMATION

TA	PACKAGE	<u>:</u> †	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	P-DIP (N)	Tube of 25	UA733CN	UA733CN	
0°C to 70°C	0010 (D)	Tube of 50	UA733CD	1147000	
	SOIC (D)	Reel of 2500	UA733CDR	UA733C	
	SOP (NS)	Reel of 2000	UA733CNSR	UA733	

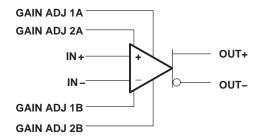
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



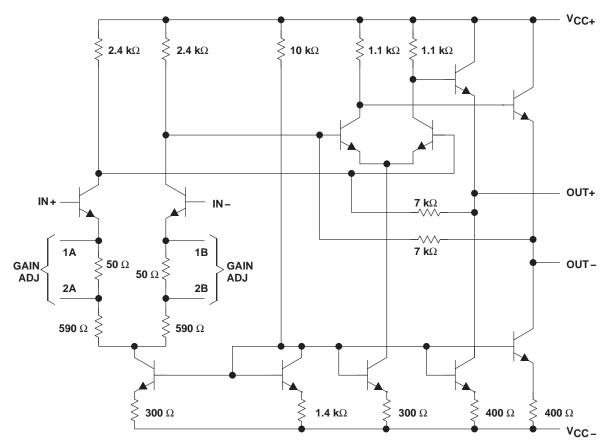
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



symbol



schematic



Component values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		μ Α733 C	μ Α733 Μ	UNIT
Supply voltage V _{CC+} (see Note 1)	8	8	V	
Supply voltage V _{CC} – (see Note 1)		- 8	- 8	V
Differential input voltage		± 5	± 5	V
Common-mode input voltage		± 6	± 6	V
Output current	10 10 n		mA	
Continuous total power dissipation	See Dissipation Rating Table			
	D package	86		
Package thermal impedance, θ_{JA} (see Notes 2 and 3)	N package	80		°C/W
	NS package	76		
Maximum junction temperature, TJ		150		°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J or U package		300	°C
Storage temperature range, T _{Stq}	- 65 to 150	- 65 to 150	°C	

[†] Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential input voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is PD = $(T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

DISSIPATION RATING TABLE

	PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
Γ	J (μΑ733M)	500 mW	11.0 mW/°C	104°C	500 mW	269 mW



electrical characteristics, $V_{CC\pm}$ = ± 6 V, T_A = 25°C

	DAMETER	FIGURE TEST CONDITIONS		GAIN	Ĺ	ι Α733C		μ Α733Μ			UNIT	
PA	RAMETER	FIGURE	TEST CONDITIONS	OPTION†	MIN	TYP	MAX	MIN	TYP	MAX	UNII	
	Large-signal			1	250	400	600	300	400	500		
A_{VD}	differential voltage	1	V _{OD} = 1 V	2	80	100	120	90	100	110	V/V	
	amplification			3	8	10	12	9	10	11		
	·			1		50			50			
BW	Bandwidth	2	$R_S = 50 \Omega$	2		90			90		MHz	
				3		200			200			
I _{IO}	Input offset current			Any		0.4	5		0.4	3	μΑ	
I _{IB}	Input bias current			Any		9	30		9	20	μΑ	
VICR	Common-mode input voltage range	1		Any	±1			±1			٧	
Voc	Common-mode output voltage	1		Any	2.4	2.9	3.4	2.4	2.9	3.4	٧	
.,	Output offset			1		0.6	1.5		0.6	1.5	.,	
V ₀₀	voltage	1		2 & 3		0.35	1.5		0.35	1	V	
VOPP	Maximum peak- to-peak output voltage swing	1		Any	3	4.7		3	4.7		٧	
				1		4			4			
r _i Input resistance	Input resistance	3	V _{OD} ≤ 1 V	2	10	24		20	24		kΩ	
				3		250			250			
r _o	Output resistance					20			20		Ω	
Ci	Input capacitance	3	V _{OD} ≤ 1 V	2		2			2		pF	
ONIDD	Common-mode	,	V _{IC} = ±1 V, f ≤ 100 kHz	2	60	86		60	86			
CMRR	rejection ration	4	V _{IC} = ±1 V, f = 5 MHz	2		70			70		dB	
k _{SVR}	Supply voltage rejection ratio (ΔV _{CC} /(ΔV _{IO})	1	$\Delta V_{CC\pm} = \pm 0.5 \text{ V}$	2	50	70		50	70		dB	
V _n	Broadband equivalent input noise voltage	5	BW = 1 kHz to 10 MHz	Any		12			12		μV	
			$R_S = 50 \Omega$	1		7.5			7.5			
^t pd	Propagation delay time	2	Output voltage	2		6.0	10		6.0	10	ns	
F.~	delay time		step = 1 V	3		3.6			3.6		1	
			$R_S = 50 \Omega$,	1		10.5			10.5			
t _r	Rise time	2	Output voltage	2		4.5	12		4.5	10	ns	
			step = 1 V	3		2.5			2.5		ヿ ー!	
I _{sink(max)}	Maximum output sink current			Any	2.5	3.6		2.5	3.6		mA	
ICC	Supply current		No load, No signal	Any		16	24		16	24	mA	

[†] The gain option is selected as follows:

Gain Option 3: All four gain-adjust pins are open.



Gain Option 1: Gain-adjust pin 1A is connected to pin 1B, and pins 2A and 2B are open.

Gain Option 2: Gain-adjust pin 1A and pin 1B are open, pin 2A is connected to pin 2B.

electrical characteristics, V_{CC \pm} = ± 6 V, T_A = 0°C to 70°C for μ A733C, – 55°C to 125°C for μ A733M

DADAMETED		FIGURE	TEGT CONDITIONS	GAIN	μ Α733C		μ Α733Μ		
	PARAMETER	FIGURE	TEST CONDITIONS	OPTION†	PTION [†] MIN		MIN	MAX	UNIT
				1	250	600	200	600	
AVD	Large-signal differential voltage amplification	1	V _{OD} = 1 V	2	80	120	80	120	V/V
	voltago amplinoation			3	8	12	8	12	
I _{IO}	Input offset current			Any		6		5	μΑ
I_{IB}	Input bias current			Any		40		40	μΑ
VICR	Common-mode input voltage range	1		Any	±1		±1		V
V	Outrot offerst college	_		1		1.5		1.5	V
V00	Output offset voltage	1		2 & 3		1.5		1.2	V
V _{OPP}	Maximum peak-to-peak output voltage swing	1		Any	2.8		2.5		V
rį	Input resistance	3	V _{OD} ≤ 1 V	2	8		8		kΩ
CMRR	Common-mode rejection ratio	4	V _{IC} = +1 V, f ≤ 100 kHz	2	50		50		dB
ksvr	Supply voltage rejection ratio (ΔV _{CC} /(ΔV _{IO})	1	$\Delta V_{CC\pm} = \pm 0.5 \text{ V}$	2	50		50		dB
I _{sink(max)}	Maximum output sink current			Any	2.5		2.2		mA
Icc	Supply current		No load, No signal	Any		27		27	mA

[†]The gain option is selected as follows:

Gain Option 1: Gain-adjust pin 1A is connected to pin 1B, and pins 2A and 2B are open.

Gain Option 2: Gain-adjust pin 1A and pin 1B are open, pin 2A is connected to pin 2B.

Gain Option 3: All four gain-adjust pins are open.

PARAMETER MEASUREMENT INFORMATION

test circuits

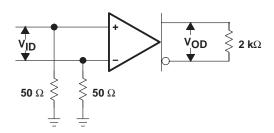


Figure 1

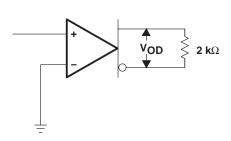


Figure 3

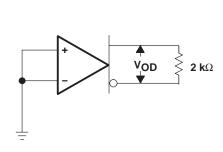


Figure 5

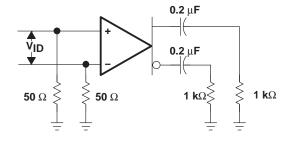


Figure 2

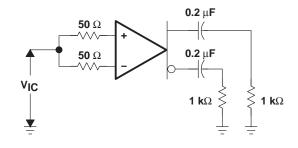
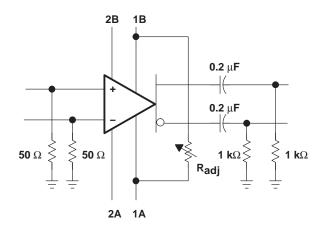


Figure 4



VOLTAGE AMPLIFICATION ADJUSTMENT

Figure 6

TYPICAL CHARACTERISTICS

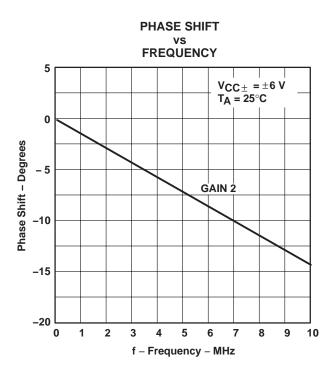


Figure 7

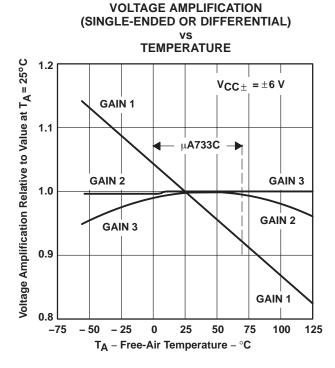


Figure 9

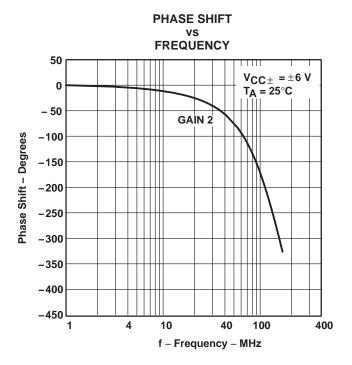
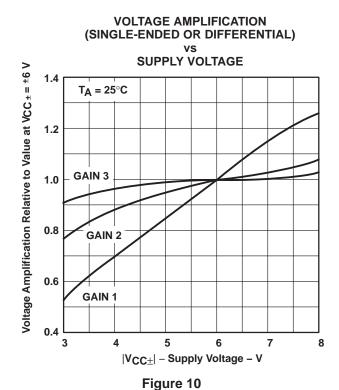


Figure 8





TYPICAL CHARACTERISTICS

DIFFERENTIAL VOLTAGE AMPLIFICATION vs RESISTANCE BETWEEN G1A AND G1B

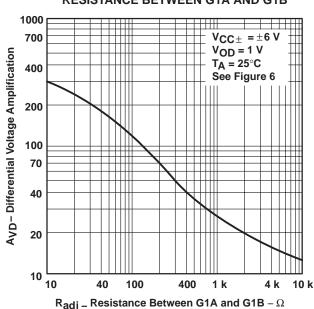


Figure 11

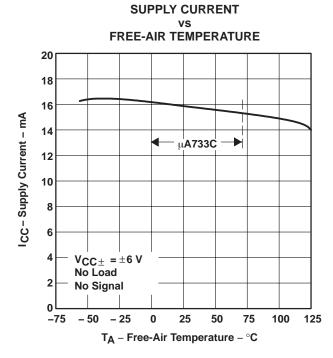


Figure 13

SINGLE-ENDED VOLTAGE AMPLIFICATION vs

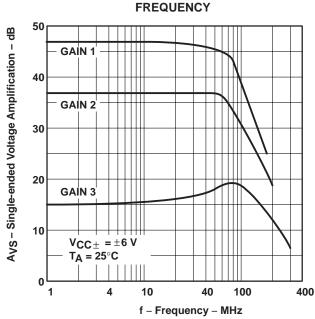


Figure 12

SUPPLY CURRENT vs SUPPLY VOLTAGE

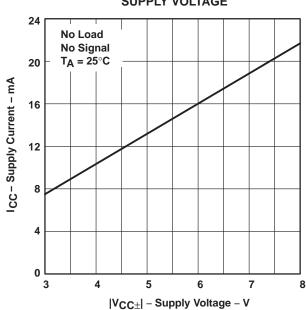


Figure 14

TYPICAL CHARACTERISTICS

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs

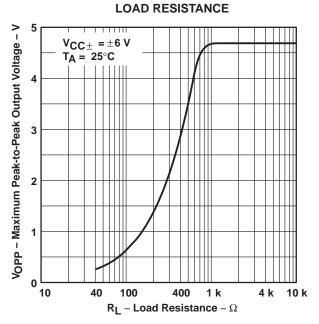


Figure 15

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs

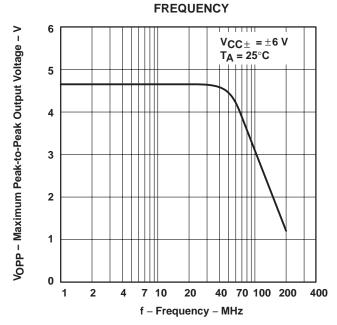


Figure 17

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs

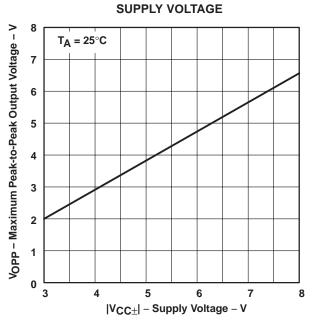


Figure 16

INPUT RESISTANCE vs FREE-AIR TEMPERATURE

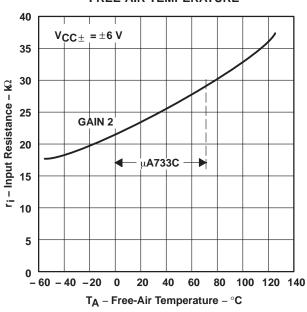


Figure 18





ti.com 5-Jul-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
84185012A	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
UA733CD	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
UA733CDE4	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
UA733CDR	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
UA733CDRE4	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
UA733CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
UA733CNSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UA733CNSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UA733MJ	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI
UA733MJB	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI
UA733MUB	OBSOLETE	CFP	U	10		TBD	Call TI	Call TI

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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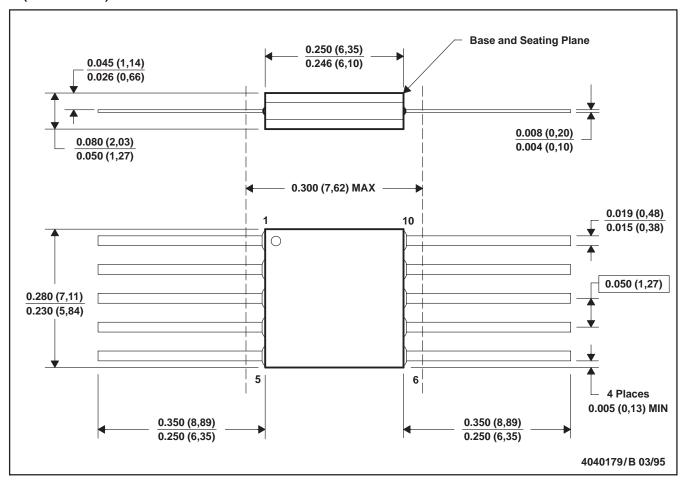
14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

U (S-GDFP-F10)

CERAMIC DUAL FLATPACK



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F10 and JEDEC MO-092AA

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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